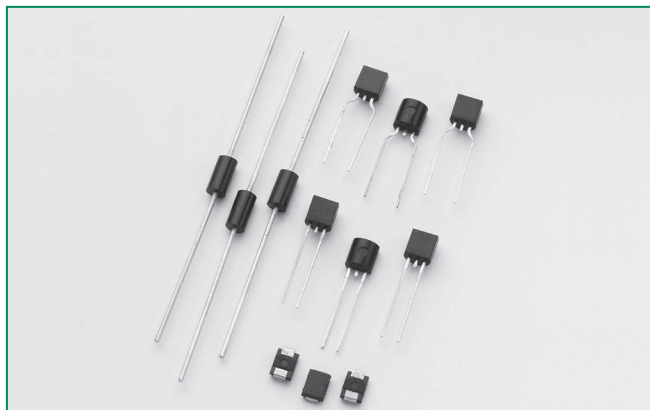


RoHS

Kxxxzy SIDAC



Description

The SIDAC is a silicon bilateral voltage triggered switch. Upon application of a voltage exceeding the SIDAC breakover voltage point, the SIDAC switches on through a negative resistance region to a low on-state voltage. Conduction continues until the current is interrupted or drops below the minimum holding current of the device.

SIDACs feature glass-passivated junctions to ensure a rugged and dependable device capable of withstanding harsh environments.

Features

- A_{Tj} R_{th}
- T_{jmax} V_b

Applications

Suitable for high voltage power supplies, natural gas igniters, high-pressure Sodium lamps, and Xenon flash ignition.

Schematic Symbol



Electrical Specifications ($T_j = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Parameters	Test Conditions	Min	Max	Unit
V_{BO}	$R_{th(j-c)}$ $R_{th(j-a)}$ $R_{th(j-amb)}$ V_b	I_{Tj} \varnothing	\varnothing	\varnothing	V
		$K \varnothing$	\varnothing	113	
		$K 10\varnothing$	104	118	
		$K 20\varnothing$	110	125	
		$K 30\varnothing$	120	138	
		$K 40\varnothing$	130	146	
		$K 50\varnothing$	140	170	
		$K 60\varnothing$	165	195	
		$\varnothing \varnothing$	205	215	
		\varnothing	220	250	
		\varnothing	240	280	
		$\varnothing \varnothing$	330		
V_{BR}	$R_{th(j-c)}$ $R_{th(j-a)}$ $R_{th(j-amb)}$ V_b	I_{Tj} \varnothing	\varnothing		V
		$K \varnothing$	\varnothing		
		$K 10\varnothing$	\varnothing		
		$K 20\varnothing$	\varnothing		
		$K 30\varnothing$	\varnothing		
		$K 40\varnothing$	\varnothing		
		$K 50\varnothing$	\varnothing		
		$K 60\varnothing$	140		
		$\varnothing \varnothing$	180		
		\varnothing	180		
		\varnothing	200		
		$\varnothing \varnothing$	200		

Electrical Specifications (T_J = 25°C, unless otherwise specified)

Symbol	Parameters	Test Conditions	Min	Max	Unit
I _{BI}		T _J < 125°C		1	A
I _{BI}		V _{BI} Wave		5	μA
V _M		I _T = 1A		1.5 3.0	V
I _H		R _L = 100Ω Wave		150	mA
R _S	$R_s = \frac{V_B - V_S}{(I_S - I_B)}$	Wave	100		Ω
I _B	Breakover Current	Wave		10	μA
I _M		t _p = 10μs		80 160	A
I _{SM}	Peak Non-repetitive Surge Current	1 cycle		20 10	A
di/dt				150	A/μs
dv/dt			1500		V/μs
T _S			-40	150	°C
T _J			-40	125	°C
R _{θJL}		DØ 5		18	°C/W
		DØ 4		30	°C/W
R _{θJC}		TØ		35	°C/W
R _{θJA}		DØ 5		5	°C/W
		TØ		9	°C/W

^b ² copper foil surface; two-ounce copper foil

Figure 1: V-I Characteristics

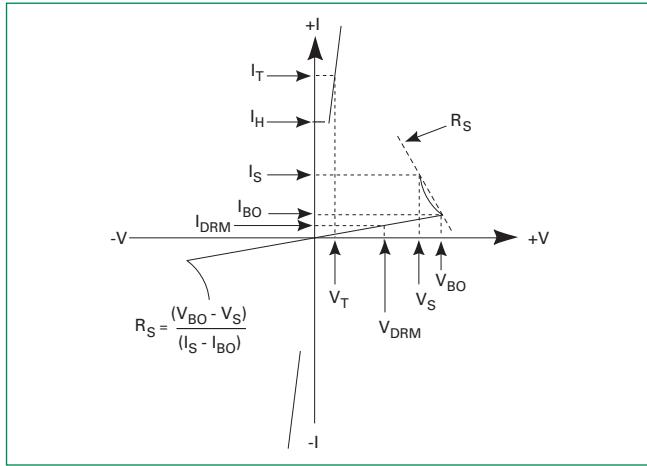


Figure 2: On-state Current vs. On-state Voltage (Typical)

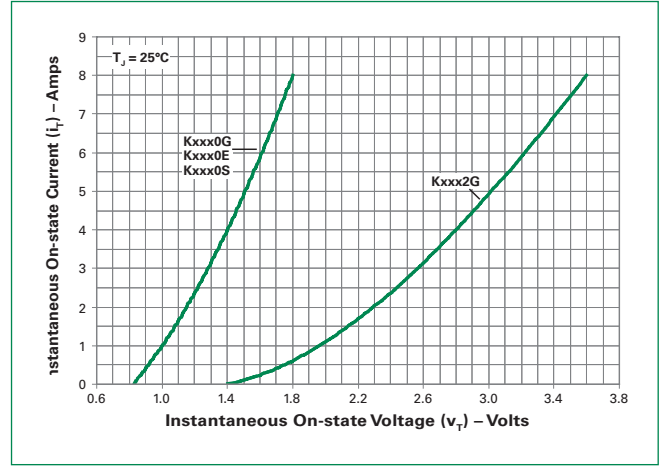


Figure 3: Power Dissipation vs. On-state Current (Typical)

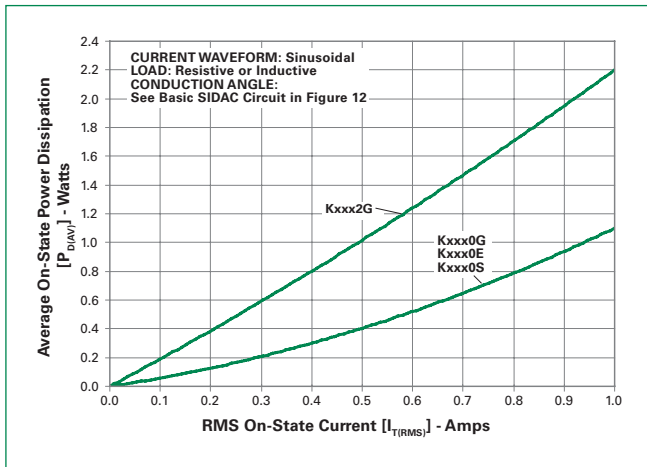


Figure 4: Repetitive Peak On-state Current (I_TRM) vs. Pulse Width at Various Frequencies

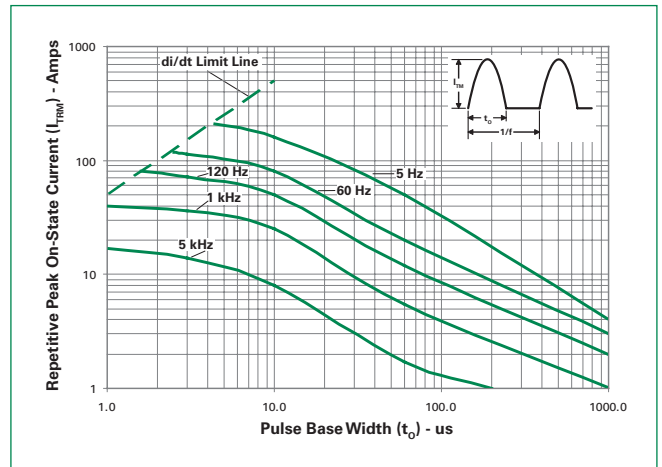


Figure 5: Peak Non-repetitive Surge Current (I_TSM) vs. Number of Cycles

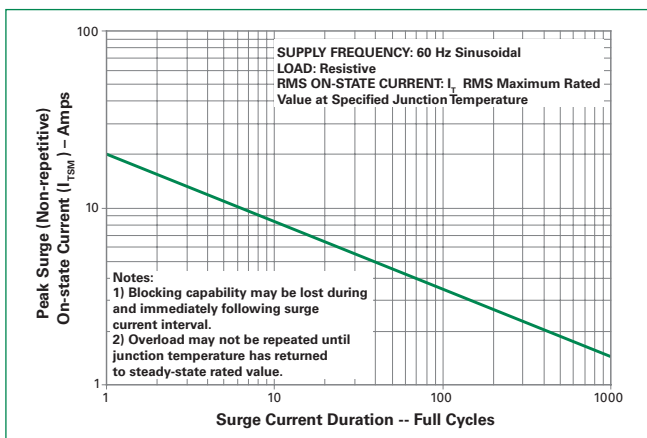


Figure 6: Normalized V_BO Change vs. Junction Temperature

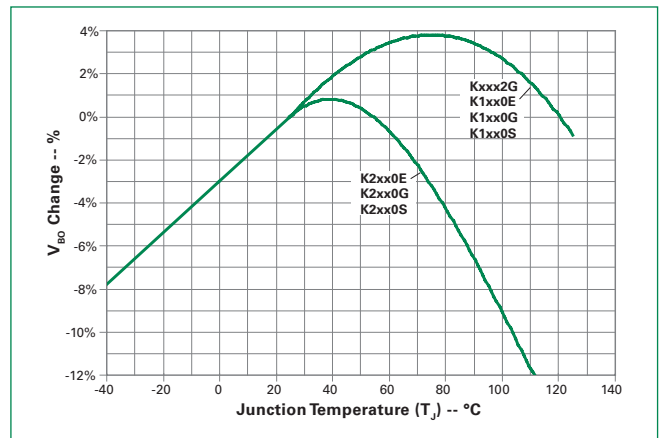


Figure 7: Normalized DC Holding Current vs. Junction Temperature

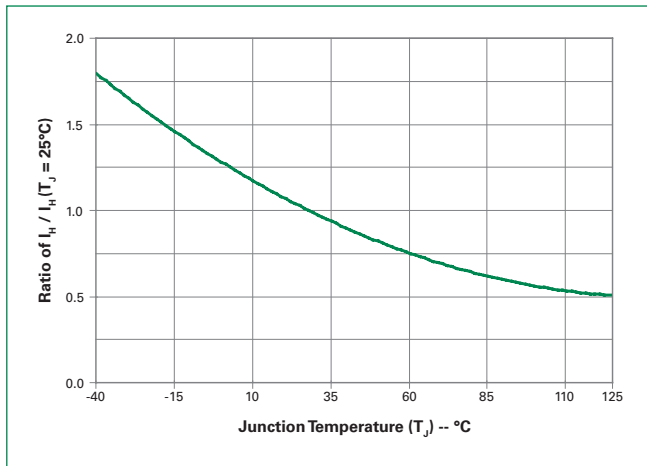


Figure 8: Maximum Allowable Case Temperature vs. RMS On-State Current

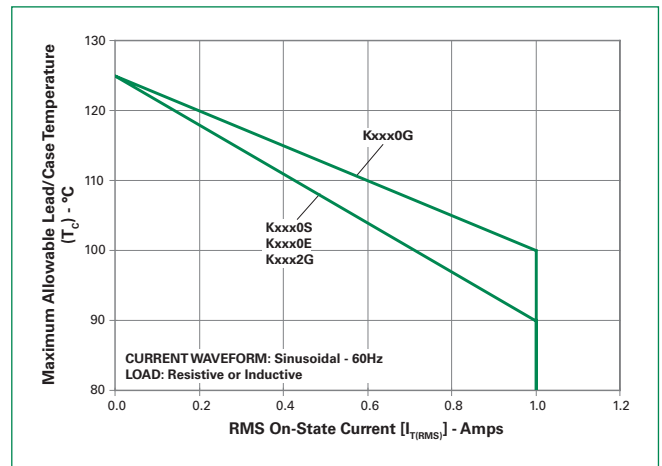


Figure 9: Maximum Allowable Ambient Temperature vs. RMS On-State Current

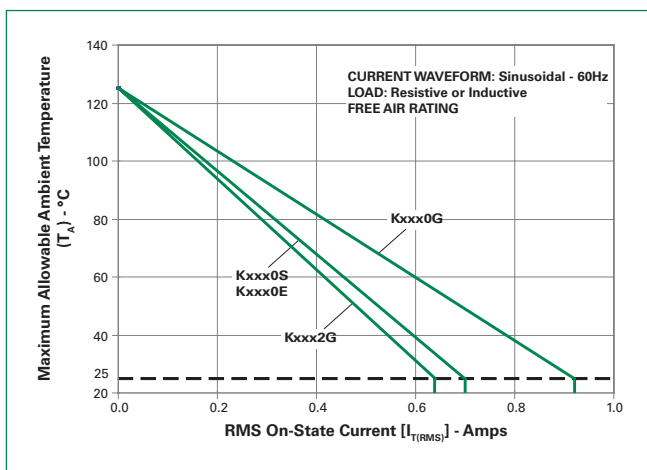


Figure 10: Normalized Repetitive Peak Breakover Current (I_{BO}) vs. Junction Temperature

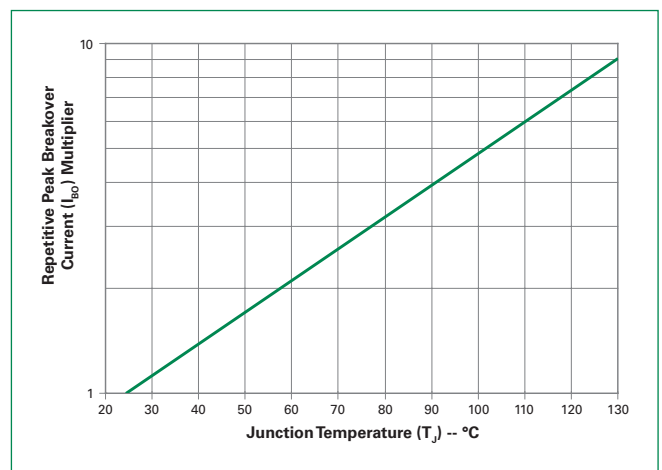


Figure 11: Dynamic Holding Current Test Circuit for SIDACs

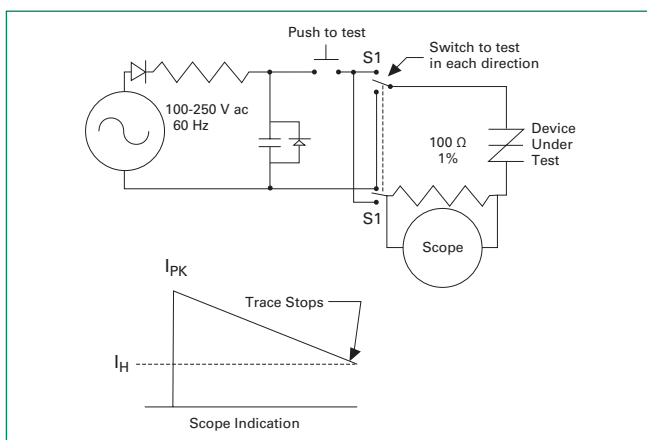


Figure 12: Basic SIDAC Circuit

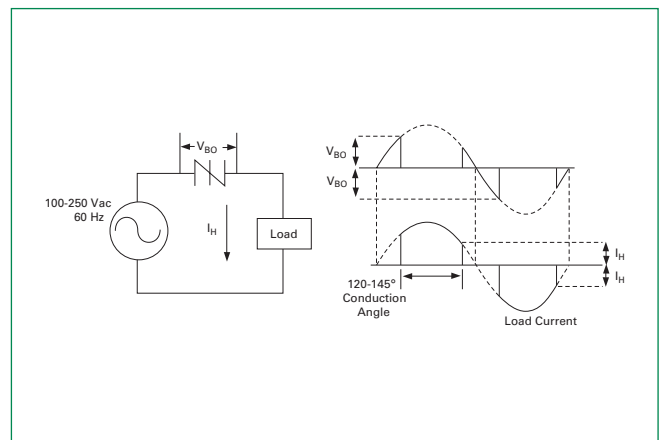


Figure 13: Relaxation Oscillator Using a SIDAC

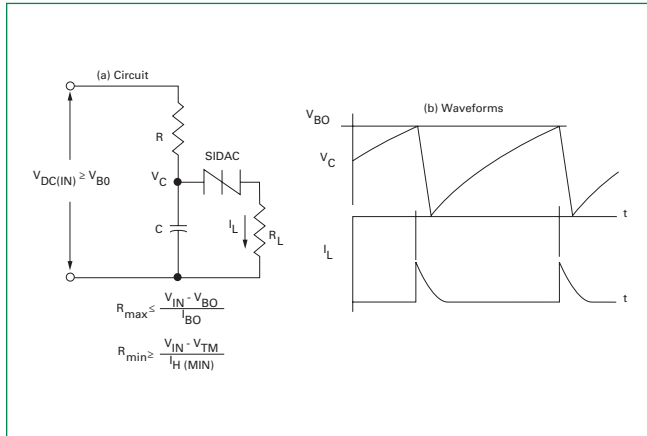


Figure 14: Low-voltage Input Circuit for Gas Ignition

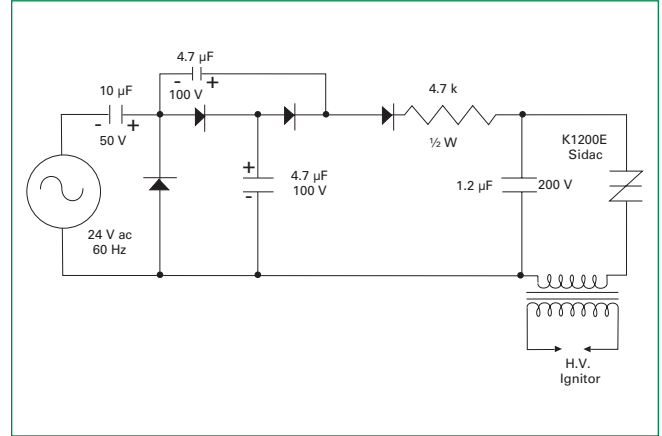


Figure 15: Comparison of SIDAC versus SCR for Gas Ignitor Circuit

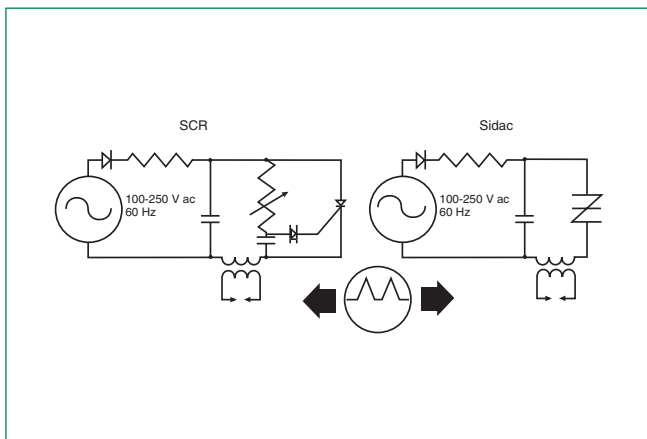


Figure 16: Xenon Lamp Flashing Circuit

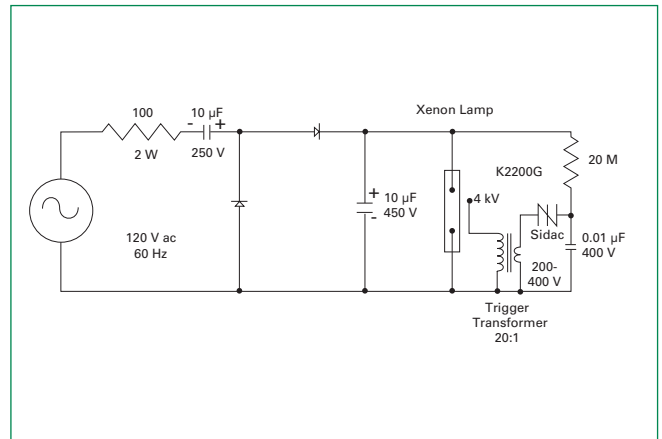
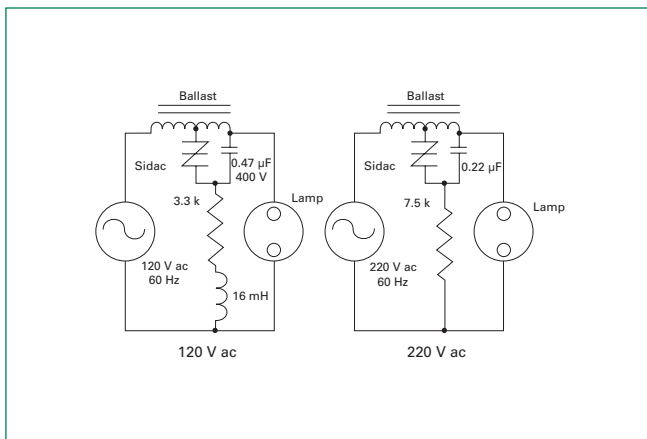
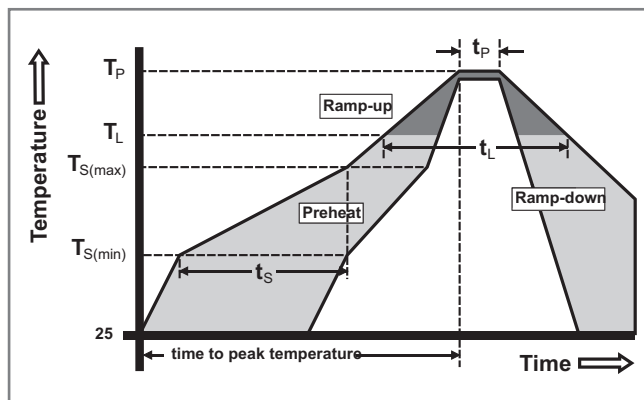


Figure 17: Typical High-pressure Sodium Lamp Firing Circuit



Soldering Parameters

Reflow Condition		
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp (T_L) to peak)		5°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		5°C/second max
Reflow	- Temperature (T_L) (Liquidus)	
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_p)		
Do not exceed		280°C



Physical Specifications

Terminal Finish	100% Dipped
Body Material	
Lead Material	

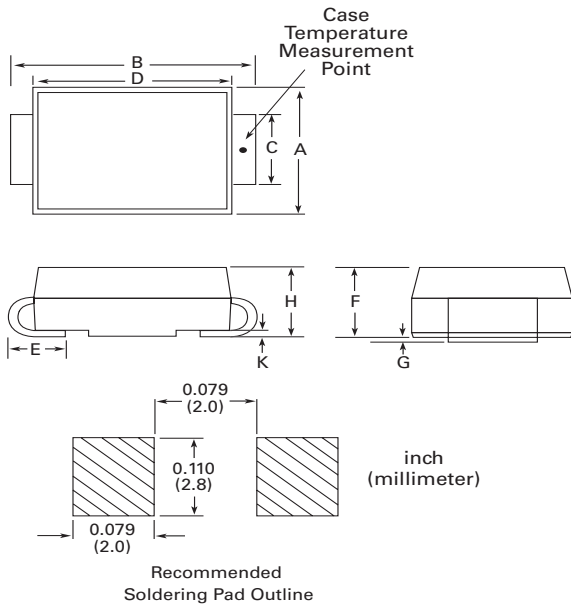
Design Considerations

Careful selection of the correct device for the application's operating parameters and environment will go a long way to ensure long life. Overheating of the device can lead to failure. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Reliability/Environmental Tests

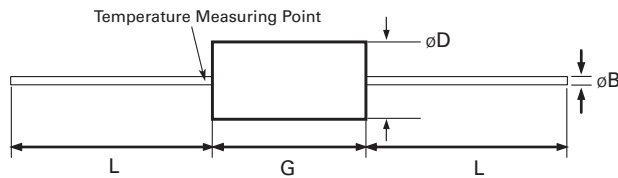
Test	Specifications and Conditions
High Temperature Voltage Blocking	08 hours
Temperature Cycling	-40°C to 150°C, 15-minute dwell, 100 cycles
Biased Temperature & Humidity	EIA/JEDEC: JESD22-A101 08 hours
High Temp Storage	150°C, 1008 hours
Low-Temp Storage	-40°C, 1008 hours
Thermal Shock	0°C to 100°C, 5-minute dwell, 100 cycles
Autoclave (Pressure Cooker Test)	EIA/JEDEC: JESD22-A102
Resistance to Solder Heat	260°C, 10 seconds
Solderability	
Lead Bend	

Dimensions — DO-214



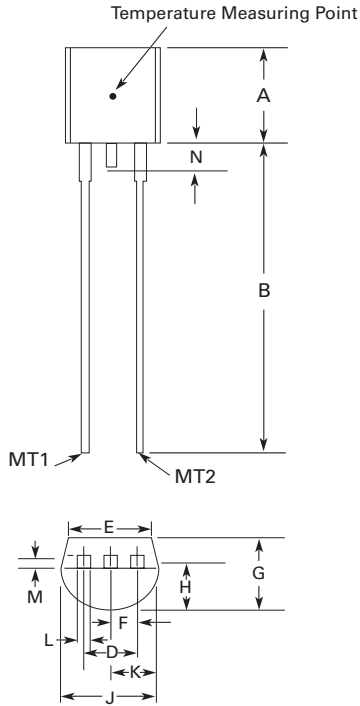
Dimension	Inches		Millimeters	
	Max	Max	Min	Max
A	0.130	0.156	3.30	3.91
B	0.201	0.220	5.10	5.60
C	0.187	0.200	4.75	5.08
D	0.187	0.181	4.75	4.60
E	0.030	0.063	0.76	1.60
F	0.008	0.008	0.20	0.20
G	0.002	0.008	0.05	0.20
H	0.000	0.104	0.00	2.65
K	0.006	0.016	0.15	0.41

Dimensions — DO-15



Dimension	Inches		Millimeters	
	Max	Max	Min	Max
øB	0.028	0.034	0.71	0.864
øD	0.120	0.140	3.048	3.556
G	0.235	0.235	5.965	6.858
L	1.000	1.000	25.400	25.400

Dimensions — TO-92 with Type 70 Lead Form



Dimension	Inches		Millimeters	
	Max	Max	Min	Max
A	0.76	0.8	2	8
B	0.500		12	
D	0	0.105	2.41	8
E	0.150		3.81	
F	0.046	0.054	1.16	13
G	0.135	0.145	3.43	3.68
H	0.088	0	2.23	2.44
J	0.76	0.186	2	2
K	0.088	0	2.23	2.44
L	0.013	0.19	0.33	0.48
M	0.013	0.17	0.33	0.43
N		0.060		1.52

Notes:

1. T₁ is the temperature measuring point.
2. All dimensions are in millimeters unless otherwise indicated.

Product Selector

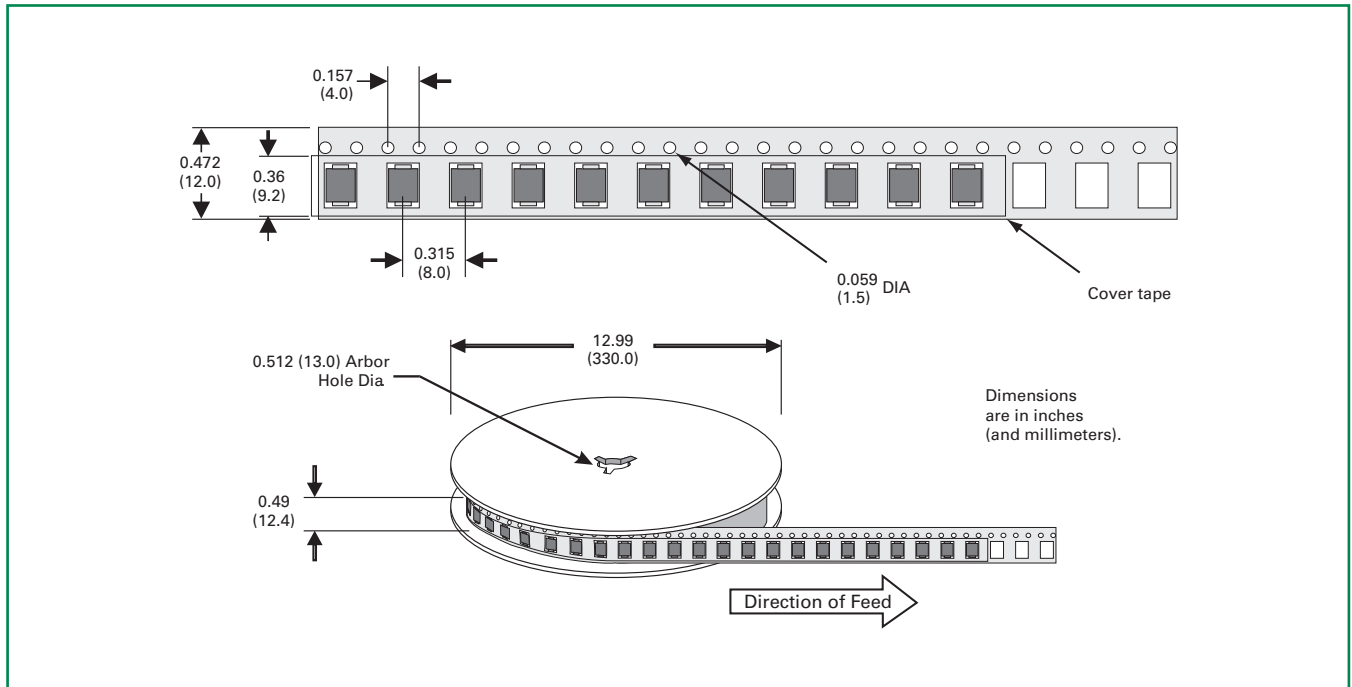
Part Number	Switching Voltage Range		Blocking Voltage	Packages		
	V _{BO} Minimum	V _{BO} Maximum	V _{DRM}	DO-15	DO-214	TO-92
K 0 0	0	0	0	K 0 G	K 0 S	K 0 0
K 0 0	0	1.3V	0	K1050G	K1050S	K 0 0
K 10 0	10	1.8V	0	K1100G	K1100S	K 10 0
K 20 0	10	1.8V	0	K1200G	K1200S	K 20 0
K 30 0	10	1.8V	0	K1300G	K1300S	K 30 0
K 40 0	10	1.8V	0	K1400G	K1400S	K 40 0
K 50 0	10	1.8V	0	K1500G	K1500S	K 50 0
K 60 0	15	1.8V	10		K1800S	
K 00 0	10	2.5	10	K2000G	K2000S	K 00 0
K 0 0	10	2.5	10	K2002G		
K 0 0	0	0	10	K2200G	K2200S	K 0 0
K 0 0	0	0	10	K2202G		
K 0 0	0	0	10	K2400G	K2400S	K 0 0
K 0 0	0	0	10	K2402G		
K 0 0	0	0	0.0	K2500G	K2500S	K 0 0
K 0 0	0	0	0.0	K2502G		
K 0 0	0	0	0.0	K3002G		

Packing Options

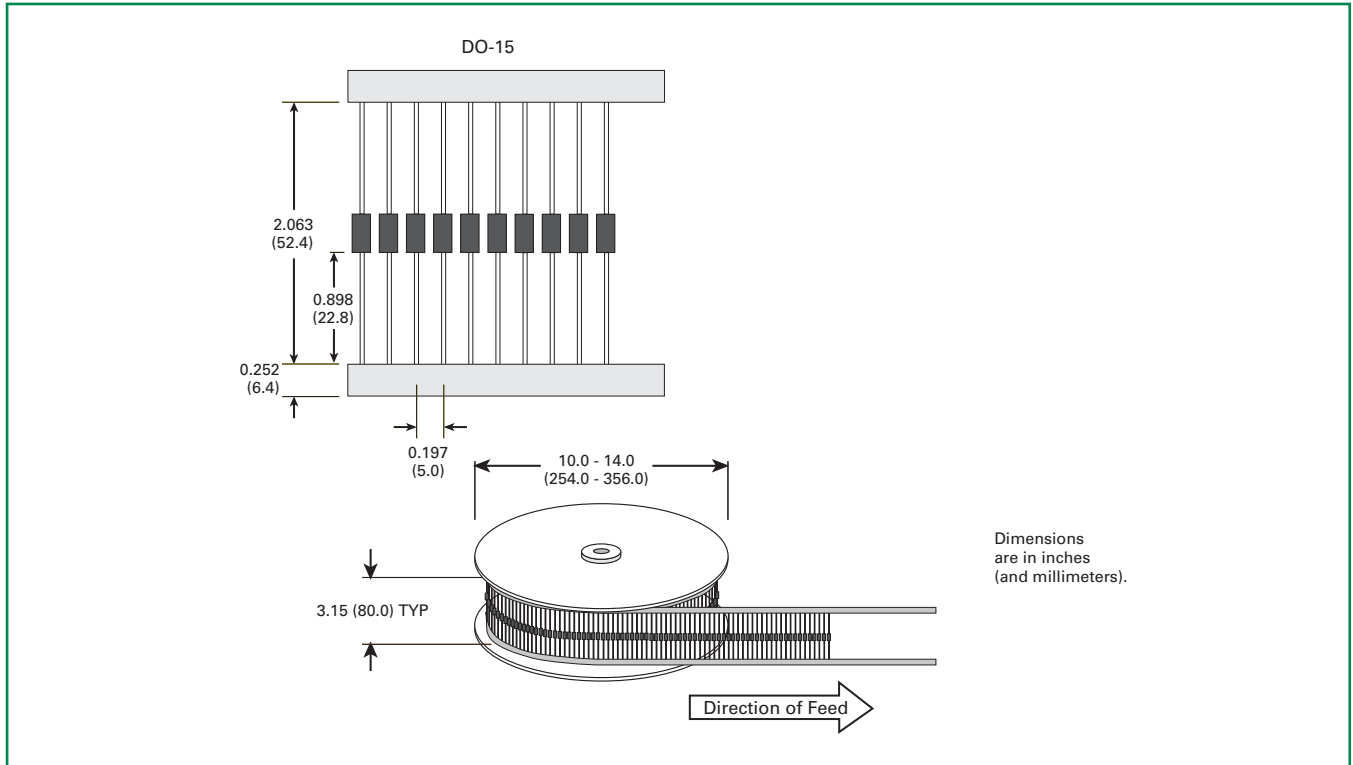
Part Number	Marking	Weight	Packaging Mode	Base Quantity
Kxxx0G	Kxxx0G	0.38g	Bulk	1000
	Kxxx0G	0.38g	Reel	5000
Kxxx2G	Kxxx2G	0.38g	Bulk	1000
	Kxxx2G	0.38g	Reel	5000
	KxxS	0.1g	Reel	2500
	Kxxx0E	0.0g	Bulk	2000
	Kxxx0E	0.0g	Ammo Pack	2000
	Kxxx0E	0.0g	Reel	2000
	Kxxx0E	0.0g	Reel	2000

Note: xxx or xx = voltage

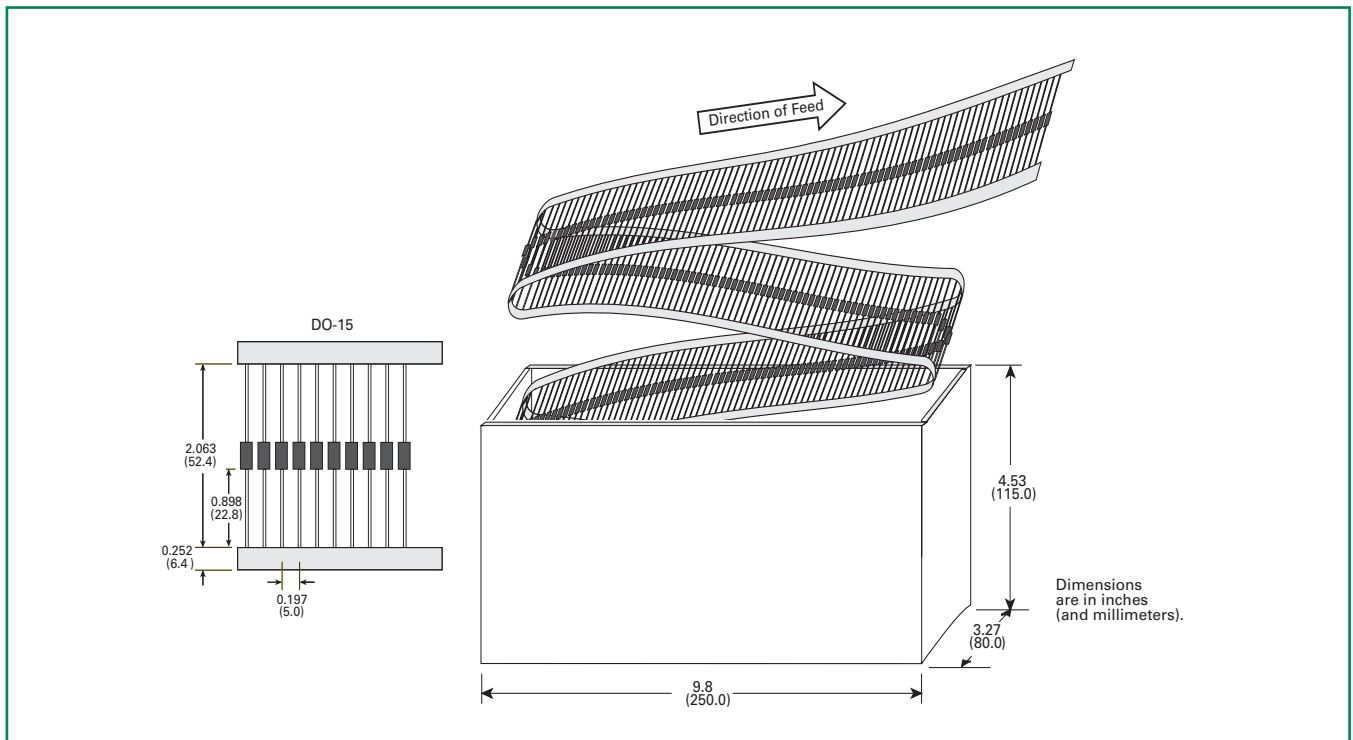
DO-214 Embossed Carrier Reel Pack (RP) Specifications



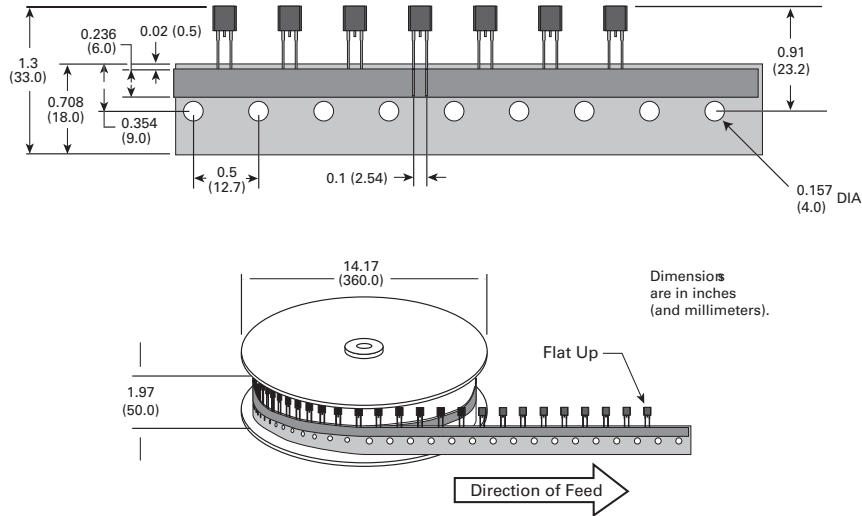
DO-15 Reel Pack (RP) Specifications



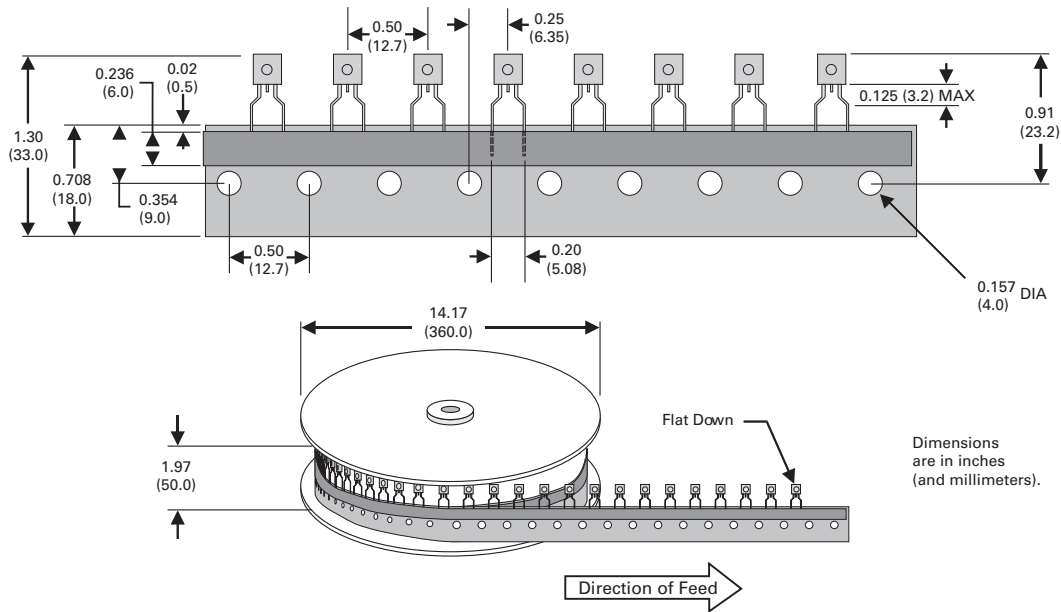
DO-15 Ammo Pack (AP) Specifications



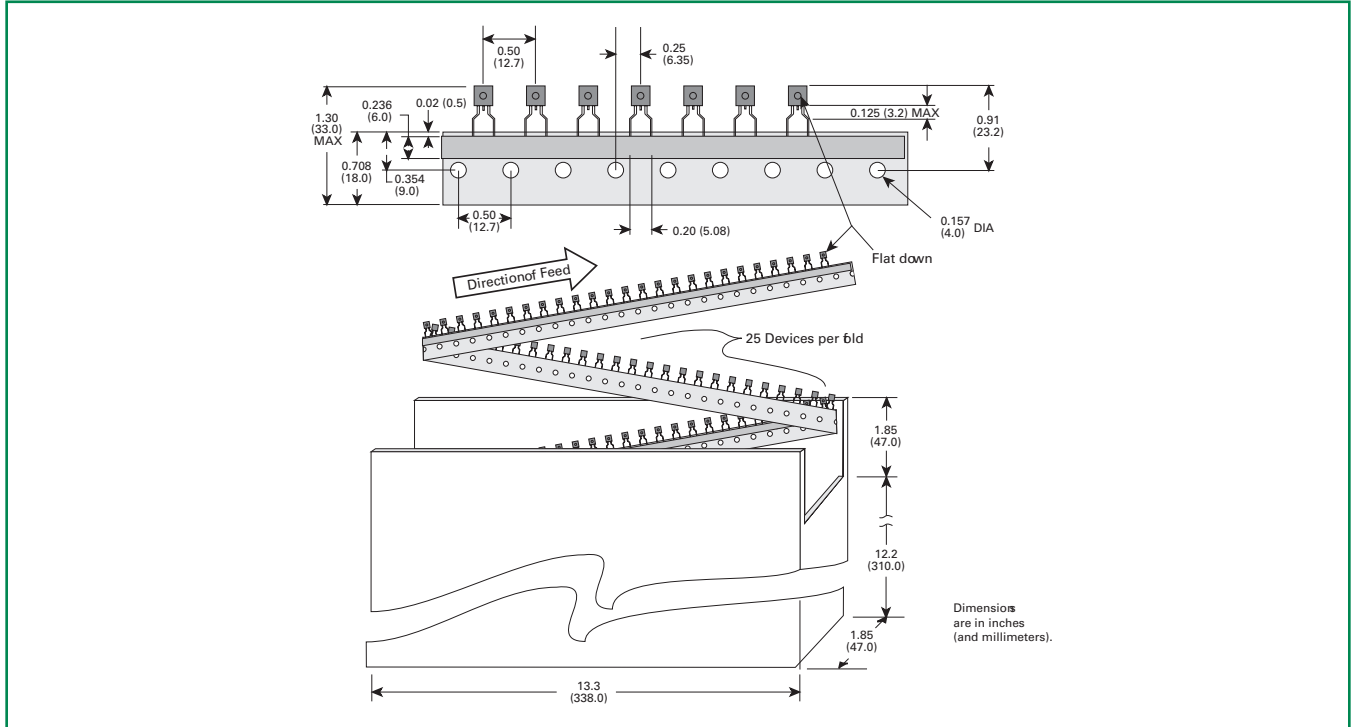
TO-92 Type 70 Reel Pack (RP3) Radial Leaded Specifications



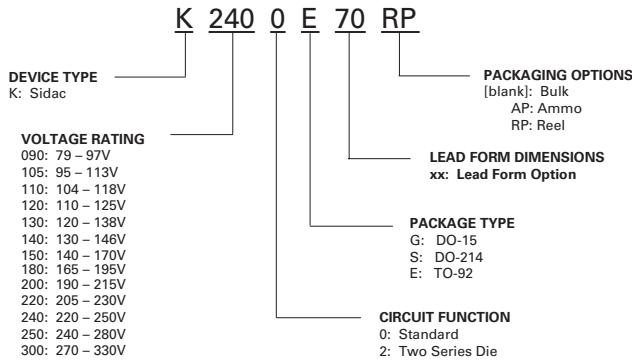
TO-92 Type 70 Reel Pack (RP2) Radial Leaded Specifications



TO-92 Type 70 Ammo Pack (AP) Radial Leaded Specifications



Part Numbering System



Part Marking System

